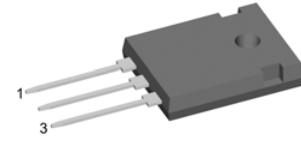
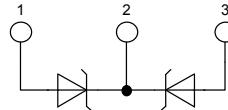


## Schottky Diode

High Performance Schottky Diode  
Low Loss and Soft Recovery  
Common Cathode

**Part number**

**DSA 60 C 45 HB**



Backside: cathode

**Features / Advantages:**

- Very low V<sub>f</sub>
- Extremely low switching losses
- low I<sub>rm</sub> values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

**Applications:**

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

**Package:**

- Housing: TO-247
- Industry standard outline
- Epoxy meets UL 94V-0
- RoHS compliant

**Ratings**

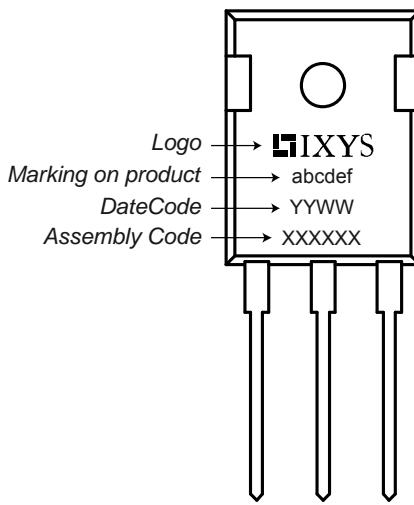
Symbol	Definition	Conditions	min.	typ.	max.	Unit
V <sub>RRM</sub>	max. repetitive reverse voltage	T <sub>vJ</sub> = 25°C			45	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 45V T <sub>vJ</sub> = 25°C		0.5		μA
		V <sub>R</sub> = 45V T <sub>vJ</sub> = 125°C		5		mA
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 30A T <sub>vJ</sub> = 25°C		0.77		V
		I <sub>F</sub> = 60A		0.96		V
		I <sub>F</sub> = 30A T <sub>vJ</sub> = 125°C		0.66		V
		I <sub>F</sub> = 60A		0.84		V
I <sub>FAV</sub>	average forward current	rectangular, d = 0.5 T <sub>C</sub> = 150°C		30		A
V <sub>F0</sub>	threshold voltage	} for power loss calculation only T <sub>vJ</sub> = 175°C		0.42		V
r <sub>F</sub>	slope resistance			5.9		mΩ
R <sub>thJC</sub>	thermal resistance junction to case			0.95		K/W
T <sub>vJ</sub>	virtual junction temperature		-55	175		°C
P <sub>tot</sub>	total power dissipation	T <sub>C</sub> = 25°C		160		W
I <sub>FSM</sub>	max. forward surge current	t = 10 ms (50 Hz), sine T <sub>vJ</sub> = 45°C		280		A
C <sub>J</sub>	junction capacitance	V <sub>R</sub> = tbdV; f = 1 MHz T <sub>vJ</sub> = 25°C		tbd		pF

Symbol	Definition	Conditions	Ratings		
			min.	typ.	max.
$I_{RMS}$	RMS current	per pin <sup>1)</sup>			50 A
$R_{thCH}$	thermal resistance case to heatsink			0.25	K/W
$T_{stg}$	storage temperature		-55		150 °C
<b>Weight</b>				6 g	
$M_D$	mounting torque		0.8		1.2 Nm
$F_c$	mounting force with clip		20		120 N

<sup>1)</sup>  $I_{RMS}$  is typically limited by: 1. pin-to-chip resistance; or by 2. current capability of the chip.

In case of 1, a common cathode/anode configuration and a non-isolated backside, the whole current capability can be used by connecting the backside.

### Product Marking

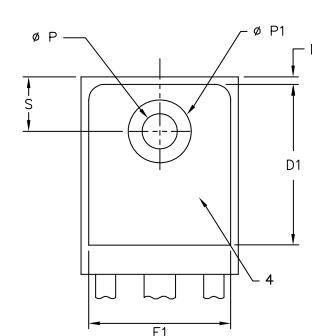
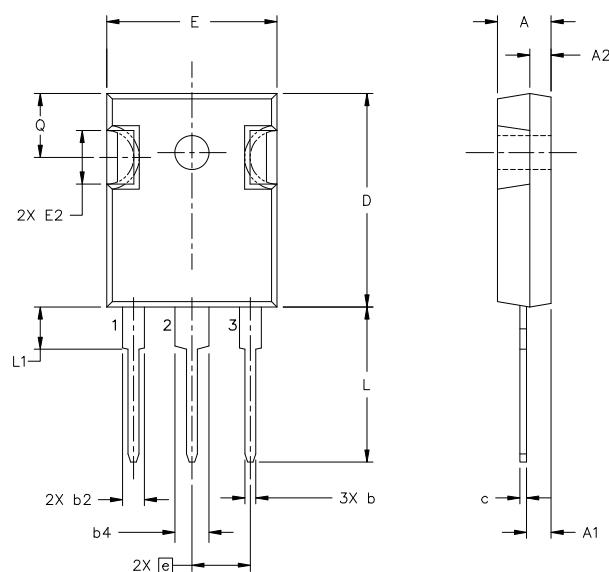


### Part number

D = Diode  
 S = Schottky Diode  
 A = low VF  
 60 = Current Rating [A]  
 45 = Reverse Voltage [V]  
 HB = TO-247AD (3)

Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Code Key
Standard	DSA 60 C 45 HB	DSA60C45HB	Tube	30	503755

## Outlines TO-247



Symbol	Inches		Millimeters	
	min	max	min	max
A	0.185	0.209	4.70	5.30
A1	0.087	0.102	2.21	2.59
A2	0.059	0.098	1.50	2.49
D	0.819	0.845	20.79	21.45
E	0.610	0.640	15.48	16.24
E2	0.170	0.216	4.31	5.48
e	0.215 BSC		5.46 BSC	
L	0.780	0.800	19.80	20.30
L1	-	0.177	-	4.49
ØP	0.140	0.144	3.55	3.65
Q	0.212	0.244	5.38	6.19
S	0.242 BSC		6.14 BSC	
b	0.039	0.055	0.99	1.40
b2	0.065	0.094	1.65	2.39
b4	0.102	0.135	2.59	3.43
c	0.015	0.035	0.38	0.89
D1	0.515	-	13.07	-
D2	0.020	0.053	0.51	1.35
E1	0.530	-	13.45	-
ØP1	-	0.291	-	7.39